RoHS COMPLIANT

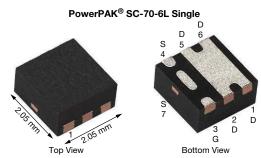
HALOGEN

FREE

www.vishay.com

Vishay Siliconix

P-Channel 20 V (D-S) MOSFET



Marking code: BQ

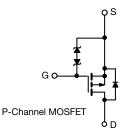
| PRODUCT SUMMARY | | | | | | | | | |
|---|--------|--|--|--|--|--|--|--|--|
| V _{DS} (V) | -20 | | | | | | | | |
| $R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5 \text{ V}$ | 0.0165 | | | | | | | | |
| $R_{DS(on)}$ max. (Ω) at $V_{GS} = -3.7 \text{ V}$ | 0.0185 | | | | | | | | |
| $R_{DS(on)}$ max. (Ω) at $V_{GS} = -2.5 \text{ V}$ | 0.0300 | | | | | | | | |
| Q _g typ. (nC) | 23 | | | | | | | | |
| I _D (A) ^a | -12 | | | | | | | | |
| Configuration | Single | | | | | | | | |

FEATURES

- TrenchFET® power MOSFET
- Thermally enhanced PowerPAK SC-70 package
 - Small footprint area
 - Low on-resistance
- 100 % R_a tested
- · Built in ESD protection with Zener diode
- Typical ESD performance: 2000 V
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · Smart phones, tablet PCs, mobile computing
 - Battery switch
- Charger switch
- Load switch



| ORDERING INFORMATION | | | | | | | |
|---------------------------------|------------------|--|--|--|--|--|--|
| Package | PowerPAK SC-70 | | | | | | |
| Lead (Pb)-free and halogen-free | SiA445EDJ-T1-GE3 | | | | | | |

| ABSOLUTE MAXIMUM RATINGS | (T _A = 25 °C, unless | otherwise noted | d) | |
|--|---------------------------------|-----------------------------------|-----------------------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Drain-source voltage | | V_{DS} | -20 | V |
| Gate-source voltage | | V_{GS} | ¬ | |
| | T _C = 25 °C | | -12 ^a | |
| Continuous drain surrent (T. 150 °C) | T _C = 70 °C | , | -12 ^a | |
| Continuous drain current (T _J = 150 °C) | T _A = 25 °C | I _D | -11.8 ^{b, c} | |
| | T _A = 70 °C | | -9.5 ^{b, c} | A |
| Pulsed drain current (t = 300 μs) | | I _{DM} | -50 | |
| Ocalia a cara da da disalia a cara | T _C = 25 °C | 1 | -12 ^a | |
| Continuous source-drain diode current | T _A = 25 °C | I _S | -2.9 b, c | |
| | T _C = 25 °C | | 19 | |
| Maximum navvar dissination | T _C = 70 °C | | 12 | w |
| Maximum power dissipation | T _A = 25 °C | P _D | 3.5 b, c | VV |
| | T _A = 70 °C | | 2.2 b, c | |
| Operating junction and storage temperature ra | nge | T _J , T _{stg} | -55 to +150 | °C |
| Soldering recommendations (peak temperature | e) ^{d, e} | • | 260 | |

| THERMAL RESISTANCE RATINGS | | | | | | | | | |
|----------------------------------|--------------|-------------------|---------|---------|------|--|--|--|--|
| PARAMETER | | SYMBOL | TYPICAL | MAXIMUM | UNIT | | | | |
| Maximum junction-to-ambient b, f | t ≤ 5 s | R _{thJA} | 28 | 36 | °C/W | | | | |
| Maximum junction-to-case (drain) | Steady state | R_{thJC} | 5.3 | 6.5 | C/VV | | | | |

- a. Package limited
- b. Surface mounted on 1" x 1" FR4 board
- t = 5 s
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-70-6L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
- f. Maximum under steady state conditions is 80 °C/W



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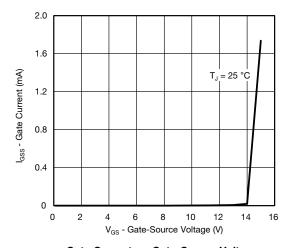
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|--------------------------------------|--|------|--------|--------|-------|
| Static | | | | • | | |
| Drain-source breakdown voltage | V_{DS} | $V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$ | -20 | - | - | V |
| V _{DS} temperature coefficient | $\Delta V_{DS}/T_{J}$ | | - | -13 | - | mV/°C |
| V _{GS(th)} temperature coefficient | ΔV _{GS(th)} /T _J | $I_D = -250 \mu A$ | - | 2.6 | - | |
| Gate-source threshold voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = -250 \mu A$ | -0.5 | - | -1.2 | V |
| | | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$ | - | - | ± 60 | |
| Gate-source leakage | I _{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$ | - | - | ± 1 | |
| Zana mata walta na aluain awanant | | V _{DS} = -20 V, V _{GS} = 0 V | - | - | -1 | μΑ |
| Zero gate voltage drain current | I _{DSS} | V _{DS} = -20 V, V _{GS} = 0 V, T _J = 55 °C | - | - | -10 | |
| On-state drain current ^a | I _{D(on)} | $V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$ | -20 | - | - | Α |
| | | V _{GS} = -4.5 V, I _D = -7 A | - | 0.0135 | 0.0165 | Ω |
| Drain-source on-state resistance ^a | R _{DS(on)} | $V_{GS} = -3.7 \text{ V}, I_D = -5 \text{ A}$ | - | 0.0150 | 0.0185 | |
| | | $V_{GS} = -2.5 \text{ V}, I_D = -5 \text{ A}$ | - | 0.0210 | 0.0300 | |
| Forward transconductance ^a | 9 _{fs} | $V_{DS} = -10 \text{ V}, I_{D} = -7 \text{ A}$ | - | 29 | - | S |
| Dynamic ^b | | | | • | | |
| Input capacitance | C _{iss} | | - | 2130 | - | pF |
| Output capacitance | C _{oss} | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$ | - | 290 | - | |
| Reverse transfer capacitance | C _{rss} | | - | 280 | - | |
| Table de de co | 0 | $V_{DS} = -10 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -12 \text{ A}$ | - | 48 | 72 | nC |
| Total gate charge | Q_g | | - | 23 | 35 | |
| Gate-source charge | Q_{gs} | $V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_D = -12 \text{ A}$ | - | 3.1 | - | |
| Gate-drain charge | Q _{gd} | | - | 6.7 | - | |
| Gate resistance | R_{g} | f = 1 MHz | 1.2 | 6 | 12 | Ω |
| Turn-on delay time | t _{d(on)} | | - | 25 | 50 | |
| Rise time | t _r | V_{DD} = -10 V, R_L = 1 Ω | - | 25 | 50 | ns |
| Turn-off delay time | t _{d(off)} | $I_D\cong$ -9.5 A, $V_{GEN}=$ -4.5 V, $R_g=$ 1 Ω | - | 55 | 110 | |
| Fall time | t _f | | - | 20 | 40 | |
| Turn-on delay time | t _{d(on)} | | - | 7 | 15 | |
| Rise time | t _r | V_{DD} = -10 V, R_L = 1 Ω | - | 10 | 20 | |
| Turn-off delay time | t _{d(off)} | $I_D\cong$ -9.5 A, $V_{GEN}=$ -10 V, $R_g=$ 1 Ω | - | 60 | 120 | |
| Fall time | t _f | | - | 17 | 35 | |
| Drain-Source Body Diode Characterist | ics | | | | | |
| Continuous source-drain diode current | Is | T _C = 25 °C | - | - | -12 | ^ |
| Pulse diode forward current I _{SM} | | | - | - | -50 | _ A |
| Body diode voltage | V_{SD} | $I_S = -9.5 \text{ A}, V_{GS} = 0 \text{ V}$ | - | -0.8 | -1.2 | V |
| Body diode reverse recovery time | t _{rr} | | - | 15 | 30 | ns |
| Body diode reverse recovery charge | Q _{rr} | $I_F = -9.5 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s},$ | - | 5 | 10 | nC |
| Reverse recovery fall time | t _a | T _J = 25 °C | - | 7 | - | |
| | | | l | | | ns |

Notes

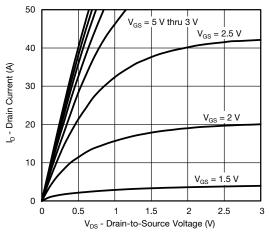
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

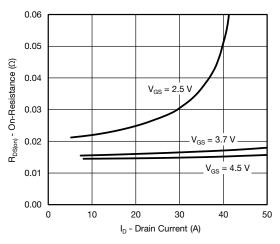




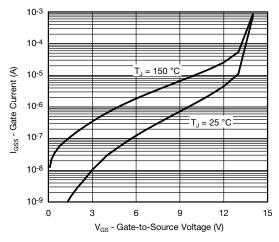
Gate Current vs. Gate-Source Voltage



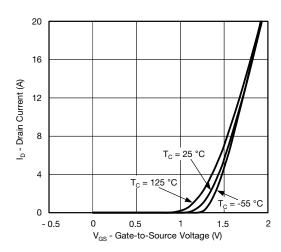
Output Characteristics



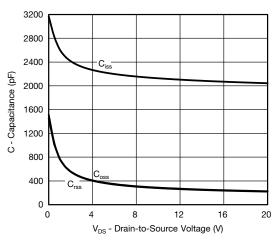
On-Resistance vs. Drain Current



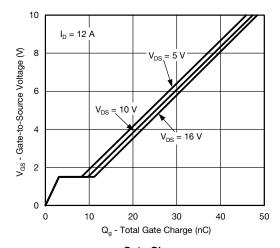
Gate Current vs. Gate-Source Voltage



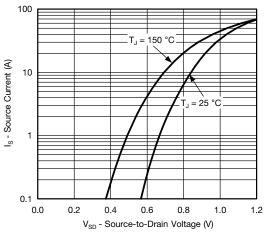
Transfer Characteristics



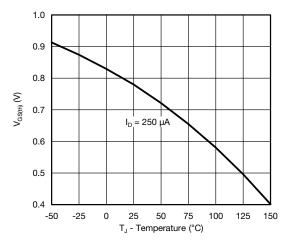




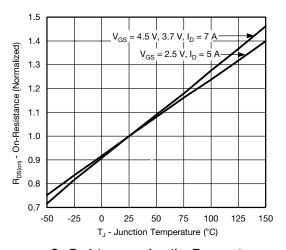
Gate Charge



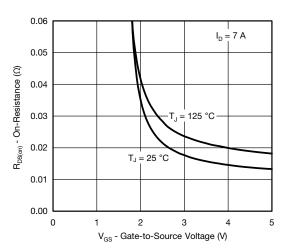
Source-Drain Diode Forward Voltage



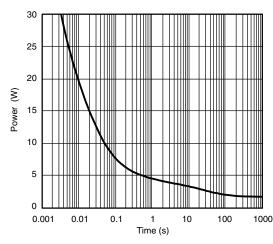
Threshold Voltage



On-Resistance vs. Junction Temperature

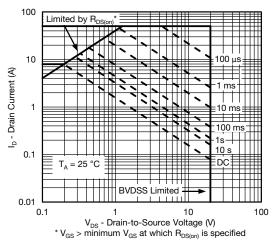


On-Resistance vs. Gate-to-Source Voltage

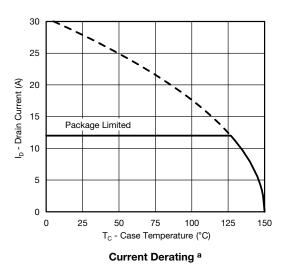


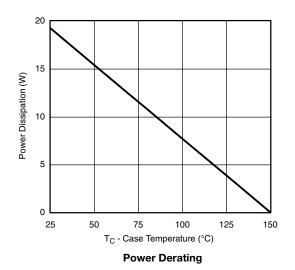
Single Pulse Power, Junction-to-Ambient





Safe Operating Area, Junction-to-Ambient

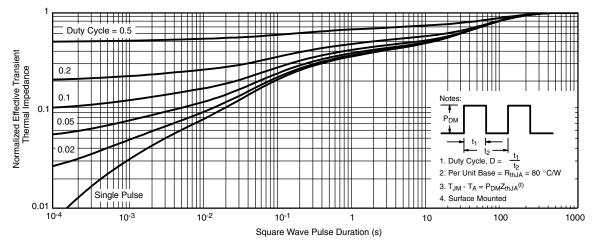




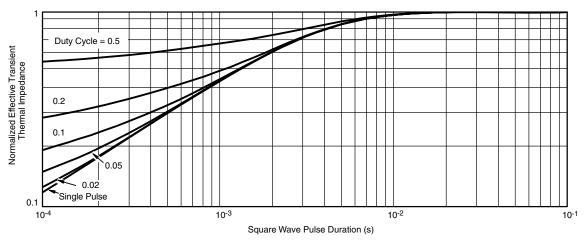
Note

a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit





Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

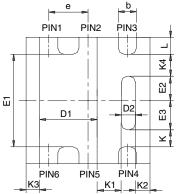
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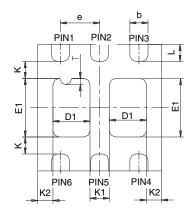




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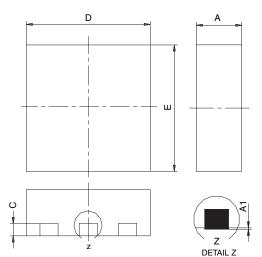
PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
 Package outline exclusive of mold flash and metal burr
 Package outline inclusive of plating

| | SINGLE PAD | | | | | | | DUAL PAD | | | | | |
|------------|-----------------------|-----------|-------|-----------|-----------|-----------|-----------|-----------|-----------|-----------|--------|-------|--|
| DIM | M | ILLIMETER | RS | | INCHES | | М | ILLIMETER | RS | | INCHES | | |
| | Min | Nom | Max | Min | Nom | Max | Min | Nom | Max | Min | Nom | Max | |
| Α | 0.675 | 0.75 | 0.80 | 0.027 | 0.030 | 0.032 | 0.675 | 0.75 | 0.80 | 0.027 | 0.030 | 0.032 | |
| A 1 | 0 | - | 0.05 | 0 | - | 0.002 | 0 | - | 0.05 | 0 | - | 0.002 | |
| b | 0.23 | 0.30 | 0.38 | 0.009 | 0.012 | 0.015 | 0.23 | 0.30 | 0.38 | 0.009 | 0.012 | 0.015 | |
| С | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 | |
| D | 1.98 | 2.05 | 2.15 | 0.078 | 0.081 | 0.085 | 1.98 | 2.05 | 2.15 | 0.078 | 0.081 | 0.085 | |
| D1 | 0.85 | 0.95 | 1.05 | 0.033 | 0.037 | 0.041 | 0.513 | 0.613 | 0.713 | 0.020 | 0.024 | 0.028 | |
| D2 | 0.135 | 0.235 | 0.335 | 0.005 | 0.009 | 0.013 | | | | | | | |
| E | 1.98 | 2.05 | 2.15 | 0.078 | 0.081 | 0.085 | 1.98 | 2.05 | 2.15 | 0.078 | 0.081 | 0.085 | |
| E1 | 1.40 | 1.50 | 1.60 | 0.055 | 0.059 | 0.063 | 0.85 | 0.95 | 1.05 | 0.033 | 0.037 | 0.041 | |
| E2 | 0.345 | 0.395 | 0.445 | 0.014 | 0.016 | 0.018 | | | | | | | |
| E3 | 0.425 | 0.475 | 0.525 | 0.017 | 0.019 | 0.021 | | | | | | | |
| е | | 0.65 BSC | | | 0.026 BSC | ; | 0.65 BSC | | | 0.026 BSC | | | |
| K | | 0.275 TYP | | | 0.011 TYP | 1 | 0.275 TYP | | | 0.011 TYP | | | |
| K1 | | 0.400 TYP | | | 0.016 TYP | | 0.320 TYP | | | 0.013 TYP | | | |
| K2 | | 0.240 TYP | | 0.009 TYP | | 0.252 TYP | | | 0.010 TYP | | | | |
| К3 | | 0.225 TYP | | 0.009 TYP | | | | | | | | | |
| K4 | | 0.355 TYP | | 0.014 TYP | | | | | | | | | |
| L | 0.175 | 0.275 | 0.375 | 0.007 | 0.011 | 0.015 | 0.175 | 0.275 | 0.375 | 0.007 | 0.011 | 0.015 | |
| Т | | | | | | | 0.05 | 0.10 | 0.15 | 0.002 | 0.004 | 0.006 | |
| ECN: C O | 07421 Pay C 06 Aug 07 | | | | | | | | | | | | |

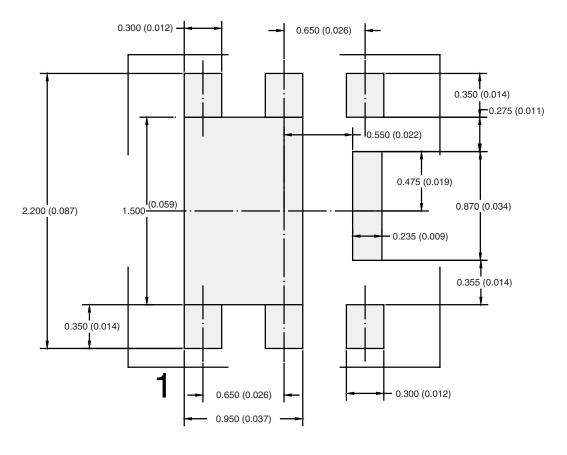
ECN: C-07431 - Rev. C, 06-Aug-07

DWG: 5934

Document Number: 73001 06-Aug-07



RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Single



Dimensions in mm/(Inches)

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